

TECHNICAL DATA  
DATA SHEET 577, REV. C

**HERMETIC POWER SCHOTTKY RECTIFIER**  
**200°C Maximum Operation Temperature**

**DESCRIPTION:** 200 VOLT, 3 AMP, HERMETIC POWER SCHOTTKY RECTIFIER IN A SHD-1/1A/1B PACKAGE.

**MAXIMUM RATINGS**

ALL RATINGS ARE @  $T_C = 25^\circ\text{C}$  UNLESS OTHERWISE SPECIFIED.

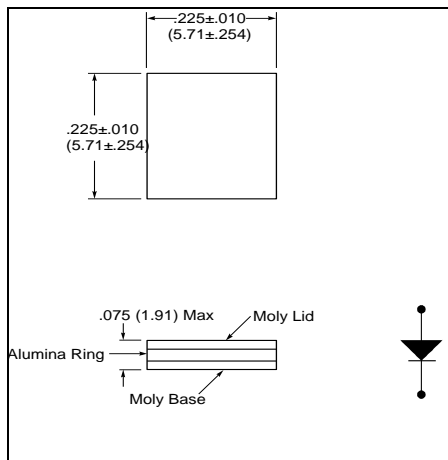
RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE	PIV	200	Volts
MAXIMUM DC OUTPUT CURRENT (With Cathode Maintained @ $T_C=100^\circ\text{C}$ )	$I_O$	3.0	Amps
MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT ( $t=8.3\text{ms}$ , Sine)	$I_{FSM}$	55	Amps
MAXIMUM JUNCTION CAPACITANCE ( $V_r=5\text{V}$ )	$C_T$	60	pF
MAXIMUM THERMAL RESISTANCE (Junction to Mounting Surface, Cathode)	$R_{\theta_{JC}}$	7.07	$^\circ\text{C/W}$
MAXIMUM OPERATING AND STORAGE TEMPERATURE RANGE	Top/Tstg	-65 to +200	$^\circ\text{C}$

**ELECTRICAL CHARACTERISTICS**

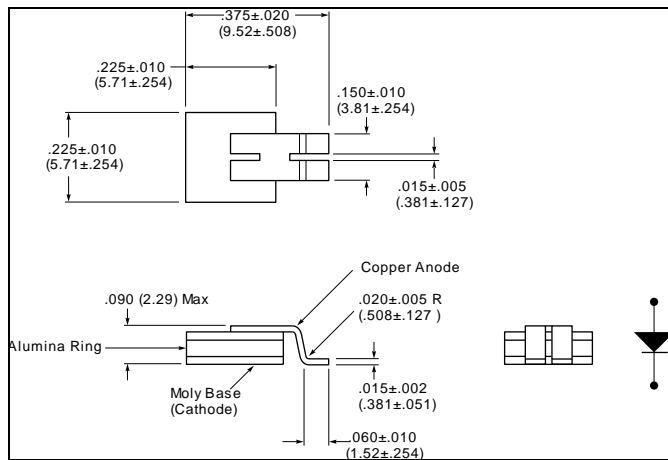
CHARACTERISTIC			
MAXIMUM FORWARD VOLTAGE DROP, Pulsed ( $I_f = 3.0$ Amps) $T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$	$V_f$	0.92 0.76	Volts
MAXIMUM REVERSE CURRENT ( $I_r$ @ 200V PIV) $T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$	$I_r$	0.07 4.6	mA

MECHANICAL DIMENSIONS: In Inches / mm

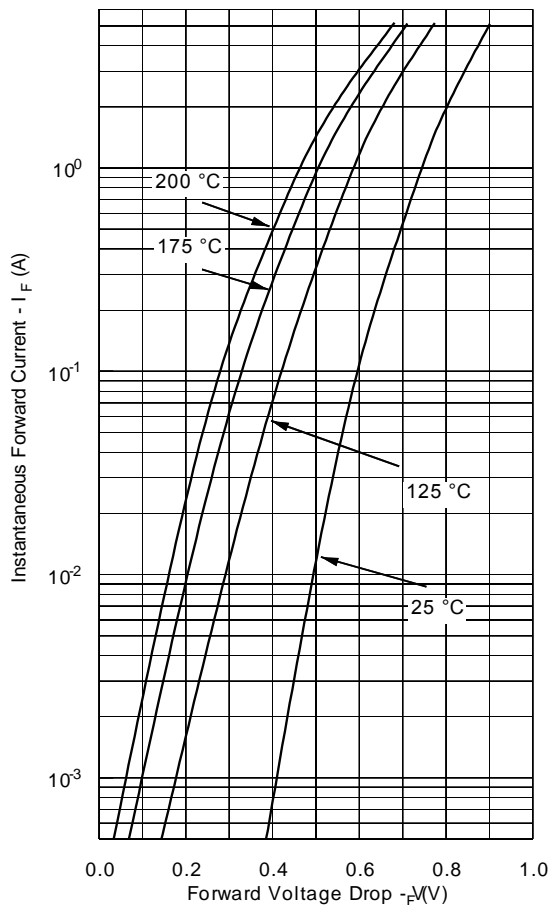
SHD-1



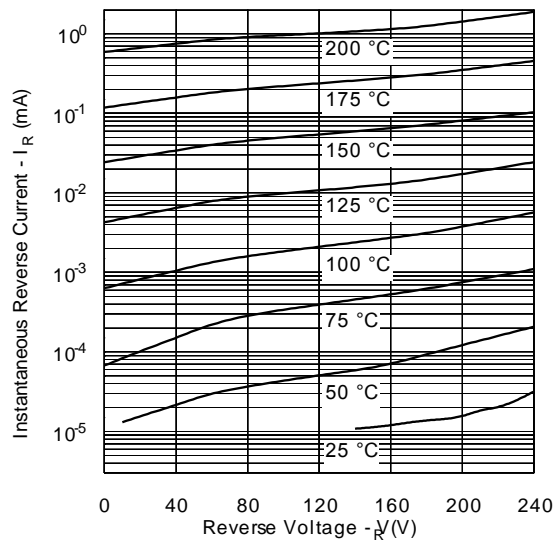
SHD-1B



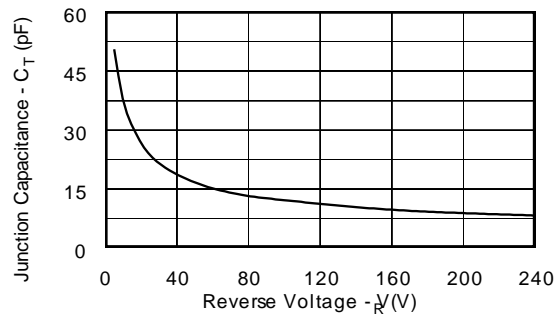
Typical Forward Characteristics



Typical Reverse Characteristics



Typical Junction Capacitance



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